# **Triacs** Silicon Bidirectional Triode Thyristors

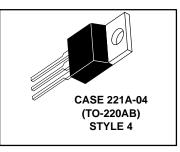
... designed primarily for full-wave ac control applications such as lighting sysjtems, heater controls, motor controls and power supplies; or wherever full-wave silicon-gate-controlled devices are needed.

- Off-State Voltages to 800 Volts
- All Diffused and Glass-Passivated Junctions for Parameter Uniformity and Stability
- Small, Rugged, Thermowatt Construction for Thermal Resistance and High Heat
  Dissipation
- Gate Triggering Guaranteed in Three Modes (MAC223 Series) or Four Modes (MAC223A Series)









### **MAXIMUM RATINGS** (T<sub>J</sub> = $25^{\circ}$ unless otherwise noted.)

Rating	Symbol	Value	Unit
Peak Repetitive Off-State Voltage (T <sub>J</sub> = -40 to 125°C)(1) (1/2 Sine Wave 50 to 60 Hz, Gate Open) MAC223-4, MAC223A4 MAC223-6, MAC223A6 MAC223-8, MAC223A8 MAC223-10, MAC223A10	Vdrm	200 400 600 800	Volts
On-State RMS Current (T <sub>C</sub> = 80°C) (Full Cycle Sine Wave 50 to 60 Hz)	IT(RMS)	25	Amps
Peak Non-repetitive Surge Current (One Full Cycle, 60 Hz, $T_C = 80^{\circ}C$ , preceded and followed by rated current)	ITSM	250	Amps
Circuit Fusing (t = 8.3 ms)	l <sup>2</sup> t	260	A <sup>2</sup> s
Peak Gate Current (t ≤ 2 μs)	IGM	2	Amps
Peak Gate Voltage (t ≤ 2 μs)	VGM	±10	Volts
Peak Gate Power (t $\leq 2 \mu s$ )	PGM	20	Watts
Average Gate Power (T <sub>C</sub> = 80°C, t $\leq$ 8.3 ms)	PG(AV)	0.5	Watts
Operating Junction Temperature Range	TJ	-40 to 125	°C
Storage Temperature Range	T <sub>stg</sub>	-40 to 150	°C
Mounting Torque	_	8	in. lb.

1. V<sub>DRM</sub> for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.



## **MAC223 Series MAC223A Series**

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	R <sub>θJC</sub>	1.2	°C/W
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	60	°C/W

**ELECTRICAL CHARACTERISTICS** ( $T_C = 25^{\circ}C$  and either polarity of MT2 to MT1 voltage unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
Peak Blocking Current <sup>(1)</sup> (V <sub>D</sub> = Rated V <sub>DRM</sub> ) $T_J = 25^{\circ}C$ $T_J = 125^{\circ}C$	IDRM			10 2	μA mA
Peak On-State Voltage (ITM = 35 A Peak, Pulse Width $\leqslant$ 2 ms, Duty Cycle $\leqslant$ 2%)	VTM	—	1.4	1.85	Volts
Gate Trigger Current (Continuous dc) $(V_D = 12 V, R_L = 100 \Omega)$ MT2(+), G(+); MT2(-), G(-); MT(+), G(-) MT2(-), G(+) "A" SUFFIX ONLY	lgt		20 30	50 75	mA
Gate Trigger Voltage (Continuous dc) $(V_D = 12 V, R_L = 100 \Omega)$ MT2(+), G(+); MT2(-), G(-); MT(+), G(-) MT2(-), G(+) "A" SUFFIX ONLY $(V_D = Rated V_{DRM}, T_J = 125^{\circ}C, R_L = 10 k)$ MT(+), G(+); MT2(-), G(-); MT2(+), G(-) MT2(-), G(+) "A" SUFFIX ONLY	VGT	 0.2 0.2	1.1 1.3 0.4 0.4	2 2.5 —	Volts
Holding Current ( $V_D$ = 12 V, $I_{TM}$ = 200 mA, Gate Open)	И	—	10	50	mA
Gate Controlled Turn-On Time ( $V_D$ = Rated $V_{DRM}$ , $I_{TM}$ = 35 A Peak, $I_G$ = 200 mA)	tgt	—	1.5		μs
Critical Rate of Rise of Off-State Voltage ( $V_D$ = Rated $V_{DRM}$ , Exponential Waveform, $T_C$ = 125°C)	dv/dt	_	40	_	V/µs
Critical Rate of Rise of Commutation Voltage (V <sub>D</sub> = Rated V <sub>DRM</sub> , $I_{TM}$ = 35 A Peak, Commutating di/dt = 12.6 A/ms, Gate Unenergized, $T_C$ = 80°C)	dv/dt(c)	-	5	-	V/µs

1. Ratings apply for open gate conditions. Devices shall not be tested with a constant current source for blocking voltage such that the voltage applied exceeds the rated blocking voltage.

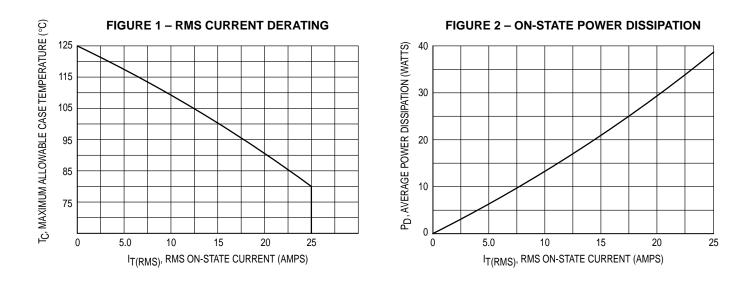
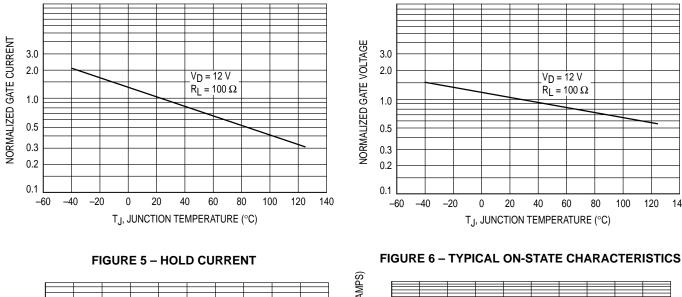


FIGURE 4 – GATE TRIGGER VOLTAGE

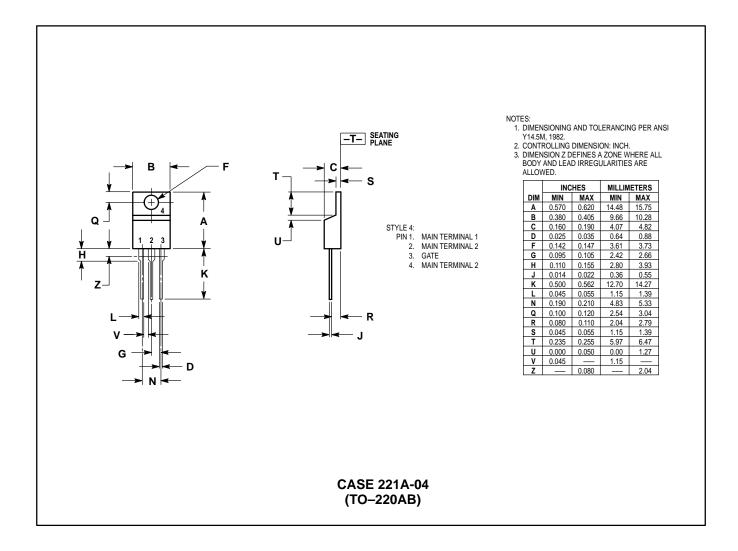


#### $i_{\mathsf{TM}},$ INSTANTANEOUS ON-STATE CURRENT (AMPS) 200 NORMALIZED HOLD CURRENT 100 50 2.0 I<sub>TM</sub> = 200 mA Gate Open 10 Tj = 25°C ≣ 1.0 5.0 0.5 1.0 0.3 0.5 0.2 0.1 0.1 3.0 4.0 2.0 -40 -20 0 20 40 60 80 100 120 140 0 1.0 -60 VTM, INSTANTANEOUS ON-STATE VOLTAGE (VOLTS) TJ, JUNCTION TEMPERATURE (°C)

### FIGURE 3 – GATE TRIGGER CURRENT

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### PACKAGE DIMENSIONS



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